Guanhua Yang

List of Publications by Year in descending order

Source: https://exaly.com/author-pdf/11009807/publications.pdf

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| 10 | 304 | 8 | 1474206 9 |
|----------------|----------------------|--------------------|--------------------|
| papers | citations | h-index | g-index |
| 10 all docs | 10 docs citations | 10 times ranked | 600 citing authors |

| # | Article | IF | CITATIONS |
|----|--|------|-----------|
| 1 | A Direct n+-Formation Process by Magnetron Sputtering an Inter-Layer Dielectric for Self-Aligned Coplanar Indium Gallium Zinc Oxide Thin-Film Transistors. Micromachines, 2022, 13, 652. | 2.9 | O |
| 2 | Spike Encoding with Optic Sensory Neurons Enable a Pulse Coupled Neural Network for Ultraviolet Image Segmentation. Nano Letters, 2020, 20, 8015-8023. | 9.1 | 59 |
| 3 | Study of Positive-Gate-Bias-Induced Hump Phenomenon in Amorphous Indium–Gallium–Zinc Oxide Thin-Film Transistors. IEEE Transactions on Electron Devices, 2020, 67, 1606-1612. | 3.0 | 16 |
| 4 | Room Temperature-Processed a-IGZO Schottky Diode for Rectifying Circuit and Bipolar 1D1R Crossbar Applications. IEEE Transactions on Electron Devices, 2019, 66, 4087-4091. | 3.0 | 22 |
| 5 | Optimization of Electrical Properties of MoS 2 Fieldâ€Effect Transistors by Dipole Layer Coulombic Interaction With Trap States. Physica Status Solidi - Rapid Research Letters, 2019, 13, 1900007. | 2.4 | 5 |
| 6 | Thickness of accumulation layer in amorphous indium-gallium-zinc-oxide thin-film transistors by Kelvin Probe Force Microscopy. Applied Physics Letters, 2019, 114, . | 3.3 | 11 |
| 7 | A Dual-Functional IGZO-Based Device With Schottky Diode Rectifying and Resistance Switching Behaviors. IEEE Electron Device Letters, 2019, 40, 24-27. | 3.9 | 20 |
| 8 | Bulkâ€Like Electrical Properties Induced by Contactâ€Limited Charge Transport in Organic Diodes: Revised Space Charge Limited Current. Advanced Electronic Materials, 2018, 4, 1700493. | 5.1 | 15 |
| 9 | Charge Transfer within the F ₄ TCNQâ€MoS ₂ van der Waals Interface: Toward Electrical Properties Tuning and Gas Sensing Application. Advanced Functional Materials, 2018, 28, 1806244. | 14.9 | 62 |
| 10 | Photoelectric Plasticity in Oxide Thin Film Transistors with Tunable Synaptic Functions. Advanced Electronic Materials, 2018, 4, 1800556. | 5.1 | 94 |